

LOW CAPACITANCE UNIDIRECTIONAL TVS DIODE

Product Summary

V_{BR} Min	I_{PP} Max	C_{IN} Typ
6V	6.5A	0.8pF

Description

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in portable applications such as cellular phones, digital cameras and MP3 players.

Applications

- Cellular Handsets
- Portable Electronics
- Computers and Peripheral

Features

- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±20kV, Contact ±20kV
- Provides ESD Protection per IEC 61000-4-4 Standard: 40A (t_p = 5/50ns)
- 1 Channel of ESD Protection
- Low Channel Input Capacitance
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

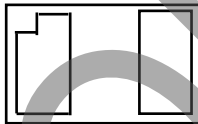
Mechanical Data

- Case: X3-DSN1006-2 (Type B)
- Case Material: Chip Scale Package
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiAu Bump. Solderable per MIL-STD-202, Method 208 ^(e4)
- Weight: 0.001 grams (Approximate)

X3-DSN1006-2 (Type B)



Top View



Bottom View



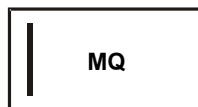
Device Schematic

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DT2042-01CSP-7B	Standard	MQ	7	8	10,000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



MQ = Product Type Marking Code
Line Denotes Pin 1

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Power Dissipation	P _{PP}	50	W	8/20μs (See Figure 1)
Peak Pulse Current	I _{PP}	6.5	A	8/20μs (See Figure 1)
ESD Protection – Air Discharge	V _{ESD_AIR}	20	kV	IEC 61000-4-2 Standard
ESD Protection – Contact Discharge	V _{ESD_CONTACT}	20	kV	IEC 61000-4-2 Standard

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Package Power Dissipation (Note 5)	P _D	250	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Standoff Voltage	V _{RWM}	—	—	5	V	—
Channel Leakage Current (Note 6)	I _{RM}	—	—	0.5	μA	V _{RWM} = 5V
Breakdown Voltage	V _{BR}	6	—	10	V	I _R = 10mA
Clamping Voltage, Positive Transients	V _{CL}	—	7.0	—	V	I _{PP} = 1A, t _p = 8/20μs
		—	7.4	—	V	I _{PP} = 2A, t _p = 8/20μs
Differential Resistance	R _{DYN}	—	0.2	—	Ω	ITLP = 1A to 10A, t _p = 100ns, I/O to GND
Channel Input Capacitance	C _{IN}	—	0.8	—	pF	V _R = 0V, f = 1MHz

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) per Diodes Incorporated's recommended pad layout, refer to <http://www.diodes.com/package-outlines.html>.

6. Short duration pulse test used to minimize self-heating effect.

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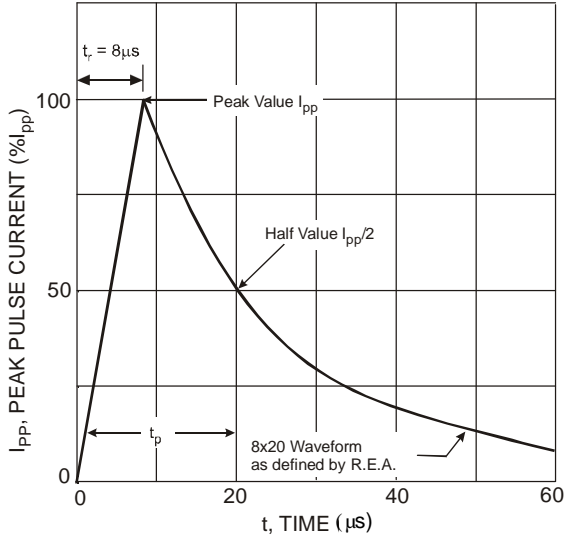


Figure 1 Pulse Waveform

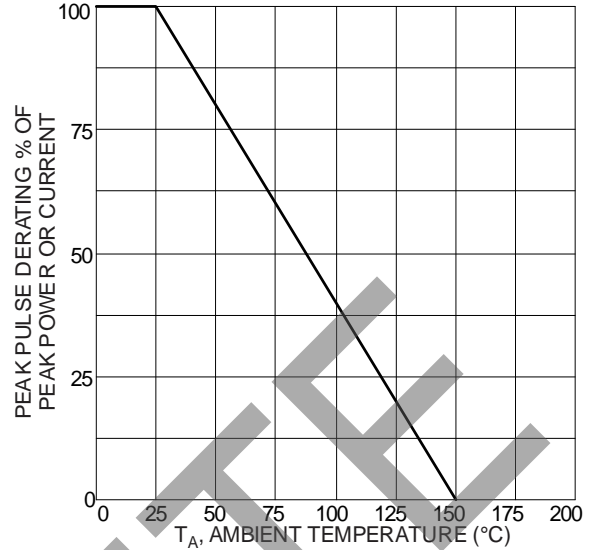


Figure 2 Pulse Deration Curve

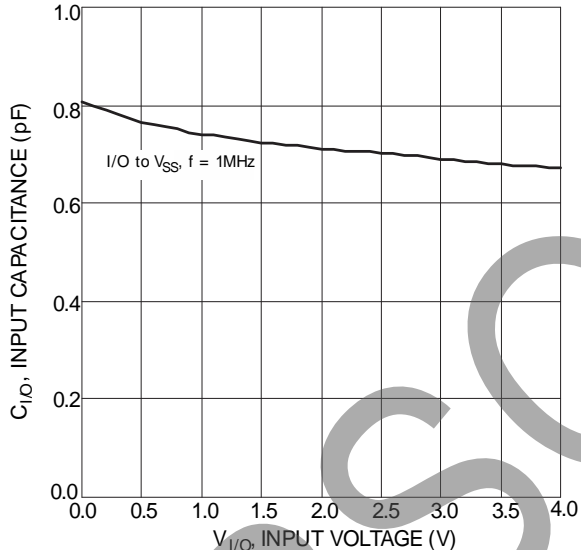


Figure 3 Input Capacitance vs. Input Voltage

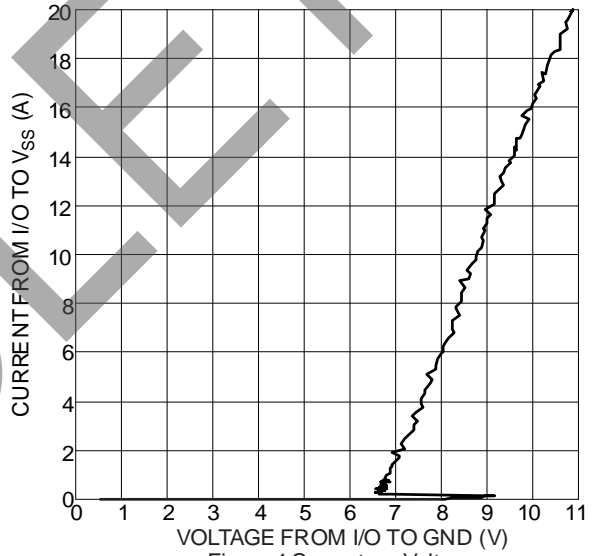


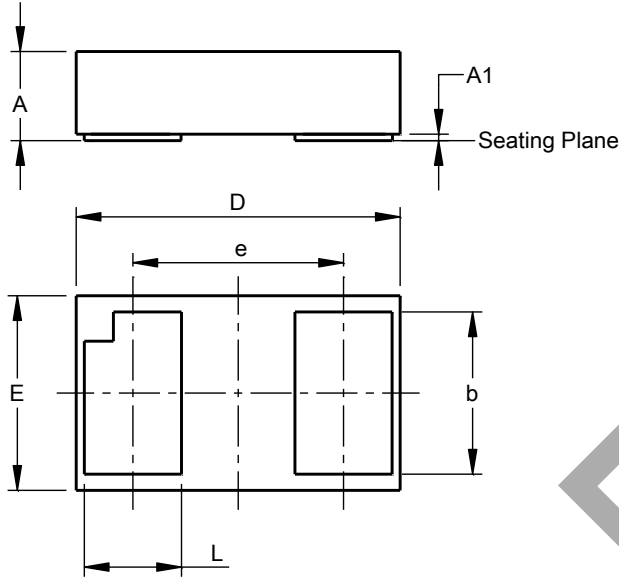
Figure 4 Current vs. Voltage

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Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X3-DSN1006-2 (Type B)

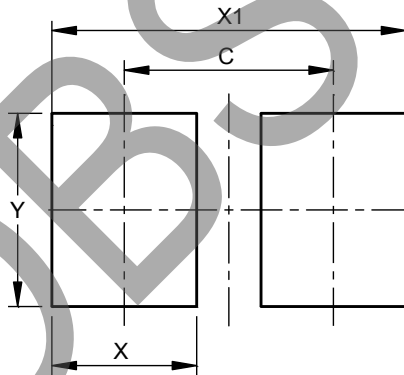


X3-DSN1006-2 (Type B)			
Dim	Min	Max	Typ
A	0.250	0.300	0.275
A1	0.00	0.02	0.01
b	0.490	0.510	0.500
D	0.975	1.025	1.00
E	0.575	0.625	0.600
e	--	--	0.650
L	0.290	0.310	0.300
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

X3-DSN1006-2 (Type B)



Dimensions	Value (in mm)
C	0.65
X	0.45
X1	1.10
Y	0.60

Note 7: Device side walls are electrically active bare silicon. Avoid contact of solder or flux on the side walls during the PCB assembly process.

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